

MBRF20H100CT - MBRF20H200CT

Isolated 20.0 AMPS. Schottky Barrier Rectifiers



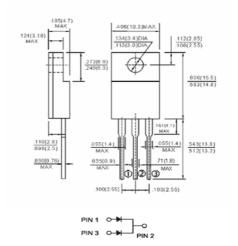
Features

- \diamond Plastic material used carries Underwriters Laboratory Classifications 94V-0
- Metal silicon junction, majority carrier conduction
- Low power loss, high efficiency
- High current capability, low forward voltage drop
- High surge capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- Guardring for overvoltage protection
- High temperature soldering guaranteed: 260°C/10 seconds,0.25"(6.35mm)from case

Mechanical Data

- Cases: ITO-220AB molded plastic
- Terminals: Pure tin plated, lead free. solderable per MIL-STD-750, Method 2026
- Polarity: As marked
- Mounting position: Any
- Mounting torque: 5 in. lbs. max Weight: 0.08 ounce, 2.24 grams

ITO-220AB



Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Rating at 25 °C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	Symbol	MBRF 20H100CT	MBRF 20H150CT	MBRF 20H200CT	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	100	150	200	V
Maximum RMS Voltage	V _{RMS}	70	105	140	V
Maximum DC Blocking Voltage	V_{DC}	100	150	200	V
Maximum Average Forward Rectified Current at T _C =133°C	I _(AV)	20			Α
Peak Repetitive Forward Current (Rated V _R , Square Wave, 20KHz) at Tc=133°C	I _{FRM}	20			Α
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I _{FSM}	150			Α
Peak Repetitive Reverse Surge Current (Note 1)	I _{RRM}	1	1.0 0.9		Α
$\begin{array}{ll} \text{Maximum Instantaneous Forward Voltage at} \\ \text{(Note 2)} & I_F = 10\text{A}, \ \text{Tc} = 25^{\circ}\text{C} \\ I_F = 10\text{A}, \ \text{Tc} = 125^{\circ}\text{C} \\ I_F = 20\text{A}, \ \text{Tc} = 25^{\circ}\text{C} \\ I_F = 20\text{A}, \ \text{Tc} = 125^{\circ}\text{C} \\ \end{array}$	V _F	0.85 0.88 0.75 0.75 0.95 0.97 0.85 0.85		V	
Maximum Instantaneous Reverse Current at Rated DC Blocking Voltage @Tc=25 °C @ Tc=125 °C	I _R	5.0 2.0			uA mA
Voltage Rate of Change, (Rated V _R)	dV/dt	10,000			V/uS
$\begin{array}{lll} RMS \ Isolation \ Voltage \ (t=1.0 \ second, \ R.H. \\ \leq 30\%, \ T_A=25\ ^{\circ}C) & (Note \ 4) \\ & (Note \ 5) \\ & (Note \ 6) \end{array}$	V _{ISO}	4500 3500 1500			V
Typical Thermal Resistance Per Leg (Note3)	R ₀ JC	3.5			°C/W
Operating Junction Temperature Range	TJ	-65 to +175			°C
Storage Temperature Range	Tstg	STG -65 to +175			°C

Notes:

- 1. 2.0 us Pulse Width, f=1.0 KHz
- 2. Pulse Test: 300us Pulse Width, 1% Duty Cycle
- 3. Thermal Resistance from Junction to Case Per Leg.
- 4. Clip Mounting (on case), where lead does not overlap heatsink with 0.110" offset.
- 5. Clip mounting (on case), where leads do overlap heatsink.
- 6. Screw mounting with 4-40 screw, where washer diameter is \leq 4.9 mm (0.19")

Version: A07



RATINGS AND CHARACTERISTIC CURVES(MBRF20H100CT - MBRF20H200CT)

FIG.1- FORWARD CURRENT DERATING CURVE

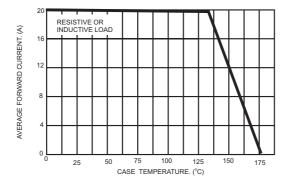


FIG.2- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT PER LEG

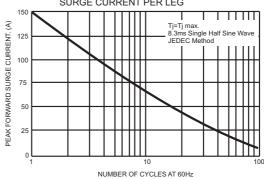


FIG.3- TYPICAL INSTANTANEOUS FORWARD

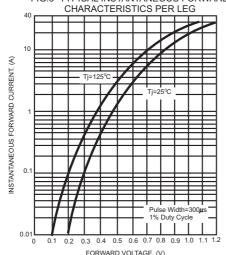


FIG.4- TYPICAL REVERSE CHARACTERISTICS

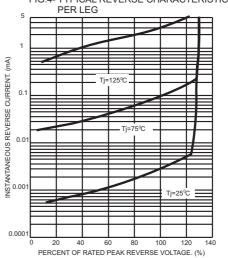


FIG.5- TYPICAL JUNCTION CAPACITANCE PER LEG

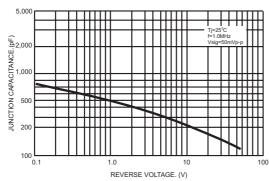


FIG.6- TYPICAL TRANSIENT THERMAL IMPEDANCE

